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Fairchild Semiconductor 1N4370A

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SEMICONDUCTOR®									
			1N437	Zeners 0A - 1N437 6A - 1N759					
Absolu	te Maxim	um Ratii	1gs * T _A = 25	5°C unless otherwise noted		Tolerand	e = 5%		
Symbol		Paramete	r	Value	Units	/			
P _D		Power Dissipation @ TL \leq 75°C, Lead Length = 3/8"		500	mW				
	Derate above	75°C		4.0	mW/°C				
T _J , T _{STG}	Operating and	d Storage Ter	mperature Ran	ge -65 to +200	°C				
						DO-35 Gla COLOR BAND DENG			
Electric	cal Charac			s otherwise noted			DTES CATHODE		
	V _Z (V)	@ I _Z = 20m	A (Note 1)		I _{ZM} (mA)	COLOR BAND DENG	DTES CATHODE		
Device	V _Z (V) Min.	@ I _Z = 20m Typ.	A (Note 1) Max.	Z _Z (Ω) @ I _Z = 20mA	(Note 2)	COLOR BAND DENG	$V_{R} = 1V$ $Ta = 125^{\circ}C$		
Device 1N4370A	V _Z (V) Min. 2.28	@ I _Z = 20m Typ. 2.4	A (Note 1) Max. 2.52	Z_Z (Ω) @ I_Z = 20mA 30	(Note 2) 150	COLOR BAND DENG I _R (μΑ) @ Ta = 25°C 100	$\mathbf{V}_{R} = \mathbf{1V}$ $\mathbf{Ta} = 125^{\circ}\mathbf{C}$ 200		
Device 1N4370A 1N4371A	V _Z (V) Min. 2.28 2.57	@ I _Z = 20m Typ. 2.4 2.7	A (Note 1) Max. 2.52 2.84	Z_Z (Ω) @ I_Z = 20mA 30 30	(Note 2) 150 135	COLOR BAND DENG I _R (μΑ) @ Ta = 25°C 100 75	$V_{R} = 1V$ $Ta = 125°C$ 200 150		
Device 1N4370A 1N4371A 1N4372A	Vz (V) Min. 2.28 2.57 2.85	@ I _Z = 20m Typ. 2.4 2.7 3.0	A (Note 1) Max. 2.52 2.84 3.15	Z _Z (Ω) @ I _Z = 20mA 30 30 29	(Note 2) 150 135 120	COLOR BAND DENG I _R (μΑ) @ Ta = 25°C 100 75 50	$V_{R} = 1V$ Ta = 125°C 200 150 100		
Device 1N4370A 1N4371A 1N4372A 1N746A	Vz (V) Min. 2.28 2.57 2.85 3.14	@ Iz = 20m Typ. 2.4 2.7 3.0 3.3	A (Note 1) Max. 2.52 2.84 3.15 3.47	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28	(Note 2) 150 135 120 110	COLOR BAND DENG I _R (μΑ) @ Ta = 25°C 100 75 50 10	$\frac{1}{2} V_{R} = 1V$ Ta = 125°C 200 150 100 30		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N747A	Vz (V) Min. 2.28 2.57 2.85 3.14 3.42	@ I _z = 20m Typ. 2.4 2.7 3.0 3.3 3.6	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24	(Note 2) 150 135 120 110 100	COLOR BAND DENG I _R (μA) @ Ta = 25°C 100 75 50 10 10 10	V _R = 1V Ta = 125°C 200 150 100 30 30		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N747A 1N748A	V _Z (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71	@ I _Z = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23	(Note 2) 150 135 120 110 100 95	COLOR BAND DENG I _R (μA) @ Ta = 25°C 100 75 50 10 10 10 10	V _R = 1V Ta = 125°C 200 150 100 30 30 30		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N747A 1N748A 1N749A	Vz (V) Min. 2.28 2.57 2.85 3.14 3.42	@ I _z = 20m Typ. 2.4 2.7 3.0 3.3 3.6	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24	(Note 2) 150 135 120 110 100	COLOR BAND DENG I _R (μA) @ Ta = 25°C 100 75 50 10 10 10	V _R = 1V Ta = 125°C 200 150 100 30 30		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N746A 1N747A 1N748A 1N749A 1N750A	V _Z (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71 4.09	@ I _Z = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9 4.3	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10 4.52	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23 22	(Note 2) 150 135 120 110 100 95 85	COLOR BAND DENG I _R (μA) @ Ta = 25°C 100 75 50 10 10 10 10 2	$ V_R = 1V Ta = 125°C 200 150 100 $		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N746A 1N747A 1N748A 1N749A 1N750A 1N751A	V _Z (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71 4.09 4.47	@ I _Z = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9 4.3 4.7	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10 4.52 4.94	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23 22 19	(Note 2) 150 135 120 110 100 95 85 75	COLOR BAND DENG I _R (μA) @ Ta = 25°C 100 75 50 10 10 10 2 2	$ \begin{array}{c} V_R = 1V \\ $		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N746A 1N748A 1N749A 1N750A 1N751A 1N752A	Vz (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71 4.09 4.47 4.85	@ I _Z = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9 4.3 4.7 5.1	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10 4.52 4.94 5.36	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23 22 19 17	(Note 2) 150 135 120 110 100 95 85 75 70	COLOR BAND DENC $ I_R (\mu A) @$ $ Ta = 25°C $ 100 75 50 10 10 10 2 2 1 1	$ \begin{array}{c} V_R = 1V \\ $		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N746A 1N748A 1N749A 1N750A 1N751A 1N752A 1N753A	Vz (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71 4.09 4.47 4.85 5.32	@ I _Z = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9 4.3 4.7 5.1 5.6	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10 4.52 4.94 5.36 5.88	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23 22 19 17 11	(Note 2) 150 135 120 110 100 95 85 75 70 65	COLOR BAND DENC $ I_R (\mu A) @$ $ Ta = 25°C $ 100 75 50 10 10 10 2 2 1 1 1	V _R = 1V Ta = 125°C 200 150 100 30 30 30 30 20 20		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N746A 1N748A 1N750A 1N751A 1N751A 1N752A 1N753A 1N754A	Vz (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71 4.09 4.47 4.85 5.32 5.89	@ I _Z = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9 4.3 4.7 5.1 5.6 6.2	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10 4.52 4.94 5.36 5.88 6.51	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23 22 19 17 11 7	(Note 2) 150 135 120 110 100 95 85 75 70 65 60	COLOR BAND DENO $I_{R} (\mu A) @$ $Ta = 25^{\circ}C$ 100 75 50 10 10 10 2 2 1 1 1 0.1	VR = 1V Ta = 125°C 200 150 100 30 30 30 30 20 20 20		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N746A 1N748A 1N750A 1N751A 1N752A 1N753A 1N753A 1N755A	Vz (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71 4.09 4.47 4.85 5.32 5.89 6.46	@ I _Z = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9 4.3 4.7 5.1 5.6 6.2 6.8	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10 4.52 4.94 5.36 5.88 6.51 7.14	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23 22 19 17 11 7 5	(Note 2) 150 135 120 110 100 95 85 75 70 65 60 55	COLOR BAND DENO $I_{R} (\mu A) @$ $Ta = 25°C$ 100 75 50 10 10 10 2 2 1 1 0 1 0 10 0 1 0 10 10 10 10 10 10 10	V _R = 1V Ta = 125°C 200 150 100 30 30 30 20 20 20 20 20 20 20 20 20 20 20		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N746A 1N748A 1N750A 1N751A 1N752A 1N753A 1N755A 1N756A	Vz (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71 4.09 4.47 4.85 5.32 5.89 6.46 7.13	@ I _Z = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9 4.3 4.7 5.1 5.6 6.2 6.8 7.5	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10 4.52 4.94 5.36 5.88 6.51 7.14 7.88	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23 22 19 17 11 7 5 6	(Note 2) 150 135 120 110 100 95 85 75 70 65 60 55 50	COLOR BAND DENO $I_{R} (\mu A) @$ $Ta = 25°C$ 100 75 50 10 10 10 2 2 1 1 0.1 0.1 0.1	VR = 1V Ta = 125°C 200 150 100 30 30 30 20 20 20 20 20 20 20 20 20 20 20 20 20 20 20 20		
	Vz (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71 4.09 4.47 4.85 5.32 5.89 6.46 7.13 7.79	@ I _Z = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9 4.3 4.7 5.1 5.6 6.2 6.8 7.5 8.2	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10 4.52 4.94 5.36 5.88 6.51 7.14 7.88 8.61	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23 22 19 17 11 7 5 6 8	(Note 2) 150 135 120 110 100 95 85 75 70 65 60 55 50 45	COLOR BAND DENO $I_{R} (\mu A) @$ $Ta = 25°C$ 100 75 50 10 10 10 2 2 1 1 0.1 0.1 0.1 0.1	$ \begin{array}{r} V_{R} = 1V \\ Ta = 125 °C \\ 200 \\ 150 \\ 100 \\ 30 \\ 30 \\ $		
Device 1N4370A 1N4371A 1N4372A 1N746A 1N746A 1N750A 1N750A 1N751A 1N752A 1N753A 1N755A 1N755A 1N756A 1N757A	Vz (V) Min. 2.28 2.57 2.85 3.14 3.42 3.71 4.09 4.47 4.85 5.32 5.89 6.46 7.13 7.79 8.65	@ Iz = 20m Typ. 2.4 2.7 3.0 3.3 3.6 3.9 4.3 4.7 5.1 5.6 6.2 6.8 7.5 8.2 9.1	A (Note 1) Max. 2.52 2.84 3.15 3.47 3.78 4.10 4.52 4.94 5.36 5.88 6.51 7.14 7.88 8.61 9.56	Z _Z (Ω) @ I _Z = 20mA 30 30 29 28 24 23 22 19 17 11 7 5 6 8 10	(Note 2) 150 135 120 110 100 95 85 75 70 65 60 55 50 45 40	COLOR BAND DENO $I_{R} (\mu A) @$ $Ta = 25°C$ 100 75 50 10 10 2 2 1 1 0 10 2 1 0 10 0 1 0 1 0	VR = 1V Ta = 125°C 200 150 100 30 30 30 20		

Notes:
2. Zener Voltage (V_Z)
The zener voltage is measured with the device junction in the thermal equilibrium at the lead temperature (T_L) at 30°C ± 1°C and 3/8" lead length.

2. Maximum Zener Current Ratings (I_{ZM})
The maximum current handling capability on a worst case basis is limited by the actual zener voltage at the operation point and the power derating curve.

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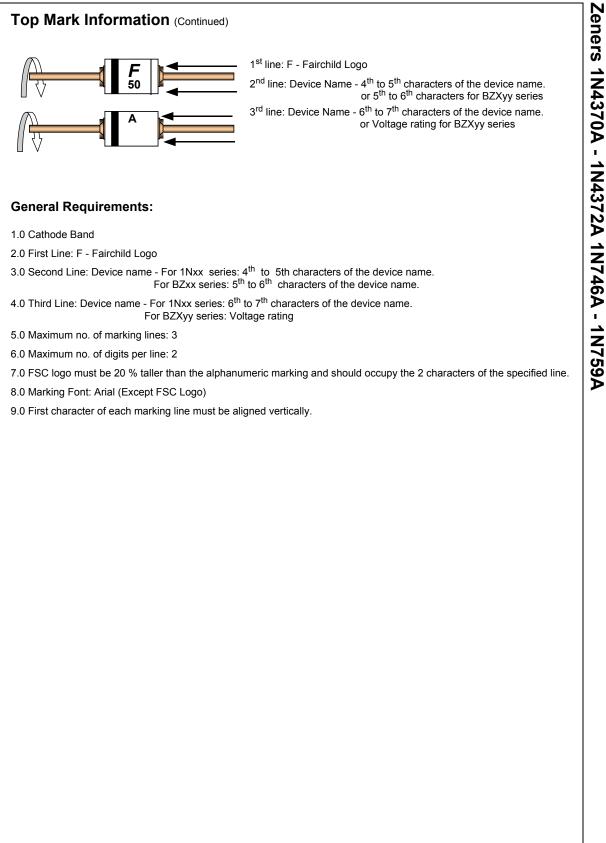
Zeners 1N4370A - 1N4372A 1N746A - 1N759A



Top Mark Information							
Device	Line 1	Line 2	Line 3				
1N4370A	LOGO	37	0A				
1N4371A	LOGO	37	1A				
1N4372A	LOGO	37	2A				
1N746A	LOGO	46	А				
1N747A	LOGO	47	А				
1N748A	LOGO	48	А				
1N749A	LOGO	49	А				
1N750A	LOGO	50	А				
1N751A	LOGO	51	А				
1N752A	LOGO	52	А				
1N753A	LOGO	53	А				
1N754A	LOGO	54	A				
1N755A	LOGO	55	А				
1N756A	LOGO	56	А				
1N757A	LOGO	57	А				
1N758A	LOGO	58	А				
1N759A	LOGO	59	А				

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Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.
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